

FFH30S60S

30 A, 600 V STEALTH™ II Diode

Features

- Stealth Recovery, trr = 40 ns (@ IF = 30 A)
- Max. Forward Voltage, V_F = 2.6 V (@ T_C = 25°C)
- · 600 V Reverse Voltage and High Reliability
- · Avalanche Energy Rated
- · RoHS Compliant

Applications

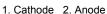
- · General Purpose
- SMPS
- · Boost Diode in Continuous Mode Power Factor Corrections
- · Power Switching Circuits

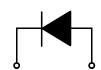
Description

The FFH30S60S is STEALTH™ II diode with soft recovery characteristics using silicon nitride passivated ion-implanted epitaxial planar construction. This device is intended for use as a freewheeling boost diode in switching power supplies and other power switching applications. Their low stored charge and hyperfast soft recovery minimize ringing and electrical noise in power switching circuits, reducing power loss in switching transistors.

Pin Assigments







1. Cathode 2. Anode

Absolute Maximum Ratings T_C = 25°C unless otherwise noted.

| Symbol | Parameter | Rating | Unit |
|-----------------------------------|---|-------------|------|
| V _{RRM} | Peak Repetitive Reverse Voltage | 600 | V |
| V _{RWM} | Working Peak Reverse Voltage | 600 | V |
| V_R | DC Blocking Voltage 600 | | V |
| I _{F(AV)} | Average Rectified Forward Current @ T _C = 102°C | 30 | Α |
| I _{FSM} | Non-Repetitive Peak Surge Current 60 Hz Single Half-Sine Wave | | Α |
| T _J , T _{STG} | Operating and Storage Temperature Range | -65 to +150 | οС |

Thermal Characteristics

| Symbol | Parameter | Rating | Unit |
|-----------------|--|--------|------|
| $R_{\theta JC}$ | Maximum Thermal Resistance, Junction to Case | 1.1 | °C/W |

Package Marking and Ordering Information

| Device Marking | Device | Package | Reel Size | Tape Width | Quantity |
|----------------|-------------|-----------|-----------|------------|----------|
| F30S60S | FFH30S60STU | TO-247-2L | - | - | 50 |

Electrical Characteristics $T_C = 25^{\circ}C$ unless otherwise noted.

| Symbol | Parameter | | Min. | Тур. | Max. | Unit |
|---|---|---|-------------|-------------------------|-------------------|---------------|
| V _F 1 | I _F = 30 A I _F = 30 A | $T_{\rm C} = 25^{\rm o}{\rm C}$ $T_{\rm C} = 125^{\rm o}{\rm C}$ | | 2.1 1.6 | 2.6 | V |
| I _R 1 | V _R = 600 V V _R = 600 V | $T_{\rm C} = 25^{\rm o}{\rm C}$ $T_{\rm C} = 125^{\rm o}{\rm C}$ | | | 100 500 | μА |
| t _{rr} | $I_F = 1 \text{ A}, di_F/dt = 100 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$ | T _C = 25°C | - | 25 | 35 | ns |
| t _{rr} I _{rr} S factor Q _{rr} | $I_F = 30 \text{ A}, \text{ di}_F/\text{dt} = 200 \text{ A}/\mu\text{s}, \text{ V}_R = 390 \text{ V}$ | T _C = 25°C | - - - | 28 2.4 0.9 34 | 40 - - - | ns A nC |
| t _{rr} I _{rr} S factor Q _{rr} | $I_F = 30 \text{ A}, \text{ di}_F/\text{dt} = 200 \text{ A/}\mu\text{s}, \text{ V}_R = 390 \text{ V}$ | T _C = 125°C | - - - | 75 6.3 0.9 236 | - - - | ns A nC |
| W _{AVL} | Avalanche Energy (L = 40 mH) | | 20 | - | - | mJ |

L = 40mH

Test Circuit and Waveforms

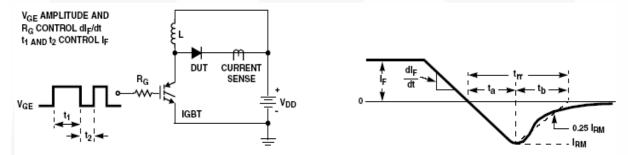


Figure 1. Diode Reverse Recovery Test Circuit & Waveform

R < 0.1Ω V_{DD} = 50V $\mathsf{EAVL} = 1/2\mathsf{LI2} \; [\mathsf{V}_{\mathsf{R}(\mathsf{AVL})}/(\mathsf{V}_{\mathsf{R}(\mathsf{AVL})} - \mathsf{V}_{\mathsf{DD}})]$ Q1 = IGBT (BV_{CES} > DUT V_{R(AVL)}) CURRENT V_{DD} SENSE V_{DD}

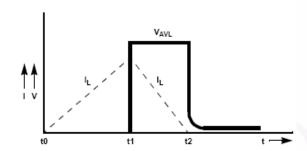


Figure 2. Unclamped Inductive Switching Test Circuit & Waveform

Notes: 1: Pulse: Test Pulse width = 300 μ s, Duty Cycle = 2%

Typical Performance Characteristics

Figure 3. Typical Forward Voltage Drop vs. Forward Current

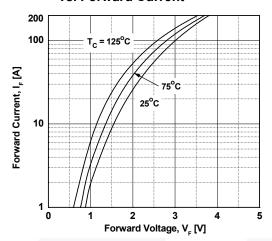


Figure 5. Typical Junction Capacitance

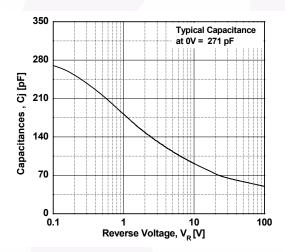


Figure 7. Typical Reverse Recovery Current vs. di_F/dt

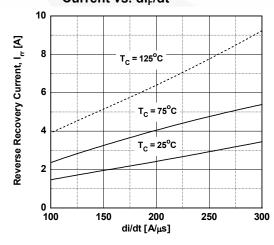


Figure 4. Typical Reverse Current vs. Reverse Voltage

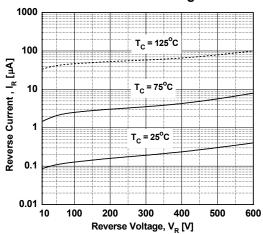


Figure 6. Typical Reverse Recovery Time vs. di_F/dt

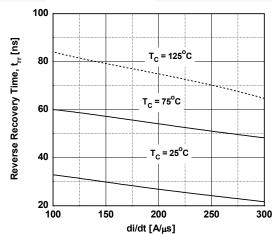
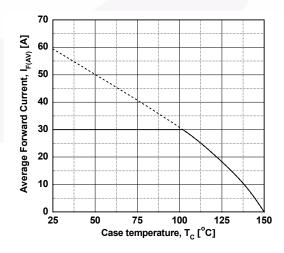
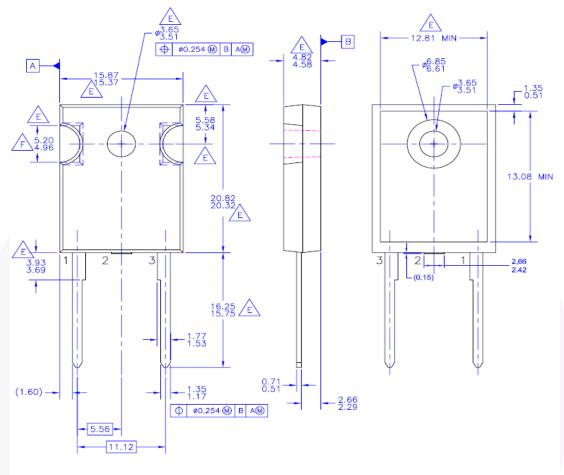


Figure 8. Forward Current Derating Curve



Mechanical Dimensions

TO-247 2L



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Figure 9. TO-247, Molded, 2LD, Jedec Option AB

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